## MMBT2222AWT1

## Preferred Device

## General Purpose Transistor

## NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 package which is designed for low power surface mount applications.

## Features

- Pb -Free Package is Available


## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector - Emitter Voltage | $\mathrm{V}_{\mathrm{CEO}}$ | 40 | Vdc |
| Collector - Base Voltage | $\mathrm{V}_{\mathrm{CBO}}$ | 75 | Vdc |
| Emitter - Base Voltage | $\mathrm{V}_{\mathrm{EBO}}$ | 6.0 | Vdc |
| Collector Current - Continuous | $\mathrm{I}_{\mathrm{C}}$ | 600 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Total Device Dissipation FR-5 Board <br> $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | 150 | mW |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\theta \mathrm{JA}}$ | 833 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction and Storage Temperature | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

ON Semiconductor ${ }^{\circledR}$
http://onsemi.com
SOLLECTOR
SASE-70
STYLE 3

## MARKING DIAGRAM



P1 = Specific Device Code
M = Date Code*

- = Pb-Free Package
(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.


## ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MMBT2222AWT1 | SC-70 | $3000 /$ Tape \& Reel |
| MMBT2222AWT1G | SC-70 <br> (Pb-Free) | 3000/Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |
| $\begin{aligned} & \text { Collector-Emitter Breakdown Voltage (Note 1) } \\ & \quad\left(I_{C}=1.0 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0\right) \end{aligned}$ | $\mathrm{V}_{\text {(BR)CEO }}$ | 40 | - | Vdc |
| Collector-Base Breakdown Voltage $\left(\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{E}}=0\right)$ | $\mathrm{V}_{\text {(BR) } \mathrm{CBO}}$ | 75 | - | Vdc |
| $\begin{aligned} & \text { Emitter - Base Breakdown Voltage } \\ & \quad\left(\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{C}}=0\right) \end{aligned}$ | $\mathrm{V}_{(\mathrm{BR}) \text { EBO }}$ | 6.0 | - | Vdc |
| Base Cutoff Current $\left(\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{EB}}=3.0 \mathrm{Vdc}\right)$ | $\mathrm{I}_{\mathrm{BL}}$ | - | 20 | nAdc |
| Collector Cutoff Current $\left(\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{EB}}=3.0 \mathrm{Vdc}\right)$ | $\mathrm{I}_{\text {CEX }}$ | - | 10 | nAdc |

ON CHARACTERISTICS (Note 1)

| DC Current Gain (Note 1) <br> $\left(I_{C}=0.1 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}\right)$ $\left(I_{C}=1.0 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}\right)$ $\left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}\right)$ ( $\mathrm{I}_{\mathrm{C}}=150 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}$ ) ( $\mathrm{I}_{\mathrm{C}}=500 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}$ ) | $\mathrm{H}_{\text {FE }}$ | $\begin{gathered} 35 \\ 50 \\ 75 \\ 100 \\ 40 \end{gathered}$ | - - - 300 - | - |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Collector-Emitter Saturation Voltage (Note 1) } \\ & \left(I_{C}=150 \mathrm{mAdc}, I_{B}=15 \mathrm{mAdc}\right) \\ & \left(I_{C}=500 \mathrm{mAdc}, I_{B}=50 \mathrm{mAdc}\right) \end{aligned}$ | $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ | - | 0.3 1.0 | Vdc |
| $\begin{aligned} & \text { Base-Emitter Saturation Voltage (Note 1) } \\ & \left(I_{C}=150 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=15 \mathrm{mAdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=500 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=50 \mathrm{mAdc}\right) \end{aligned}$ | $\mathrm{V}_{\mathrm{BE} \text { (sat) }}$ | 0.6 | 1.2 2.0 | Vdc |

SMALL-SIGNAL CHARACTERISTICS

| Current-Gain - Bandwidth Product $\left(\mathrm{I}_{\mathrm{C}}=20 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=20 \mathrm{Vdc}, \mathrm{f}=100 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | 300 | - | MHz |
| :---: | :---: | :---: | :---: | :---: |
| Output Capacitance $\left(\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\text {obo }}$ | - | 8.0 | pF |
| Input Capacitance $\left(\mathrm{V}_{\mathrm{EB}}=0.5 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\text {ibo }}$ | - | 30 | pF |
| Input Impedance <br> $\left(\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | $\mathrm{h}_{\text {ie }}$ | 0.25 | 1.25 | k $\Omega$ |
| Voltage Feedback Ratio <br> $\left(\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | $\mathrm{hr}_{\mathrm{r}}$ | - | 4.0 | X 10-4 |
| Small-Signal Current Gain <br> $\left(\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | $\mathrm{hfe}_{\text {fe }}$ | 75 | 375 | - |
| Output Admittance $\left(\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | $\mathrm{h}_{\mathrm{oe}}$ | 25 | 200 | $\mu \mathrm{mhos}$ |
| Noise Figure <br> $\left(\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{Adc}, \mathrm{R}_{\mathrm{S}}=1.0 \mathrm{k} \Omega, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | NF | - | 4.0 | dB |

## SWITCHING CHARACTERISTICS

| Delay Time | $\left(\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{Vdc}, \mathrm{V}_{\mathrm{BE}}=-0.5 \mathrm{Vdc}\right.$, $\left.\mathrm{I}_{\mathrm{C}}=150 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B} 1}=15 \mathrm{mAdc}\right)$ | $t_{d}$ | - | 10 | ns |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Rise Time |  | $\mathrm{t}_{\mathrm{r}}$ | - | 25 |  |
| Storage Time | $\begin{gathered} \left(\mathrm{V}_{\mathrm{CC}}=30 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=150 \mathrm{mAdc},\right. \\ \left.\mathrm{I}_{\mathrm{B} 1}=\mathrm{I}_{\mathrm{B} 2}=15 \mathrm{mAdc}\right) \end{gathered}$ | $\mathrm{t}_{\text {s }}$ | - | 225 | ns |
| Fall Time |  | $t_{f}$ | - | 60 |  |

1. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$.

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## SWITCHING TIME EQUIVALENT TEST CIRCUITS



Figure 1. Turn-On Time
Figure 2. Turn-Off Time


Figure 3. DC Current Gain


Figure 4. Collector Saturation Region

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Figure 5. Turn-On Time


Figure 7. Frequency Effects


Figure 9. Capacitances


Figure 6. Turn-Off Time


Figure 8. Source Resistance Effects


Figure 10. Current-Gain Bandwidth Product

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Figure 11. "On" Voltages


Figure 12. Temperature Coefficients

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## PACKAGE DIMENSIONS

SC-70 (SOT-323)
CASE 419-04
ISSUE M


NOTES.

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

|  | MILLIMETERS |  |  | INCHES |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |  |
| A | 0.80 | 0.90 | 1.00 | 0.032 | 0.035 | 0.040 |  |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |  |
| A2 | 0.7 REF |  |  | 0.028 REF |  |  |  |
| b | 0.30 | 0.35 | 0.40 | 0.012 | 0.014 | 0.016 |  |
| c | 0.10 | 0.18 | 0.25 | 0.004 | 0.007 | 0.010 |  |
| D | 1.80 | 2.10 | 2.20 | 0.071 | 0.083 | 0.087 |  |
| E | 1.15 | 1.24 | 1.35 | 0.045 | 0.049 | 0.053 |  |
| e | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |  |
| e1 | 0.65 BSC |  |  | 0.026 BSC |  |  |  |
| L | 0.425 REF |  |  |  | 0.017 REF |  |  |
| HE | 2.00 | 2.10 | 2.40 | 0.079 | 0.083 | 0.095 |  |

STYLE 3:
PIN 1. BASE
2. EMITTER 2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*

*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

[^0]
## PUBLICATION ORDERING INFORMATION

## LITERATURE FULFILLMENT

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